

Electronic Supplementary Information

For

**Ti₃C₂T_x MXene based Flexible Zn-ion Microsupercapacitor with Redox-Active Electrolyte for
integrated Pressure Sensing Application**

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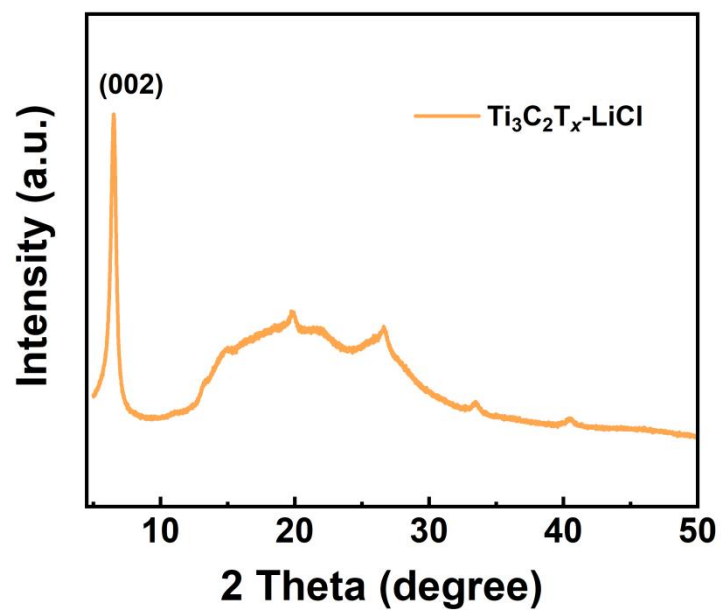


Fig. S1 The XRD patterns of the mono-layer $\text{Ti}_3\text{C}_2\text{T}_x\text{-LiCl}$ MXene.

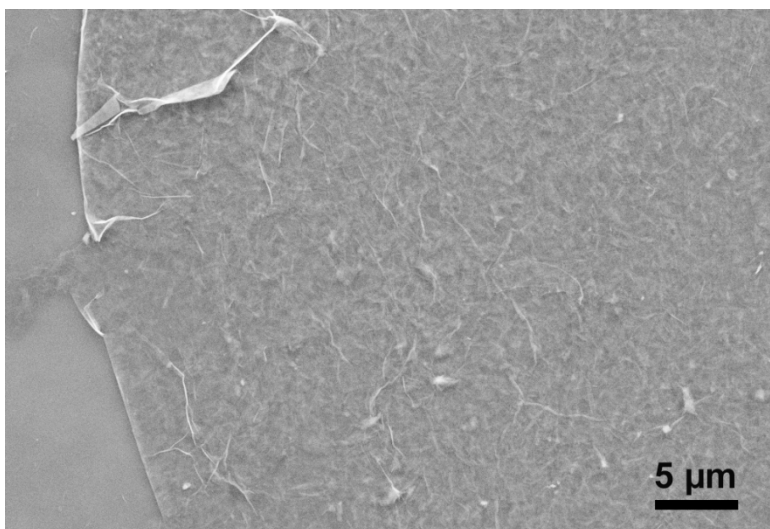


Fig. S2 The SEM image of the mono-layer $\text{Ti}_3\text{C}_2\text{T}_x\text{-LiCl}$ MXene.

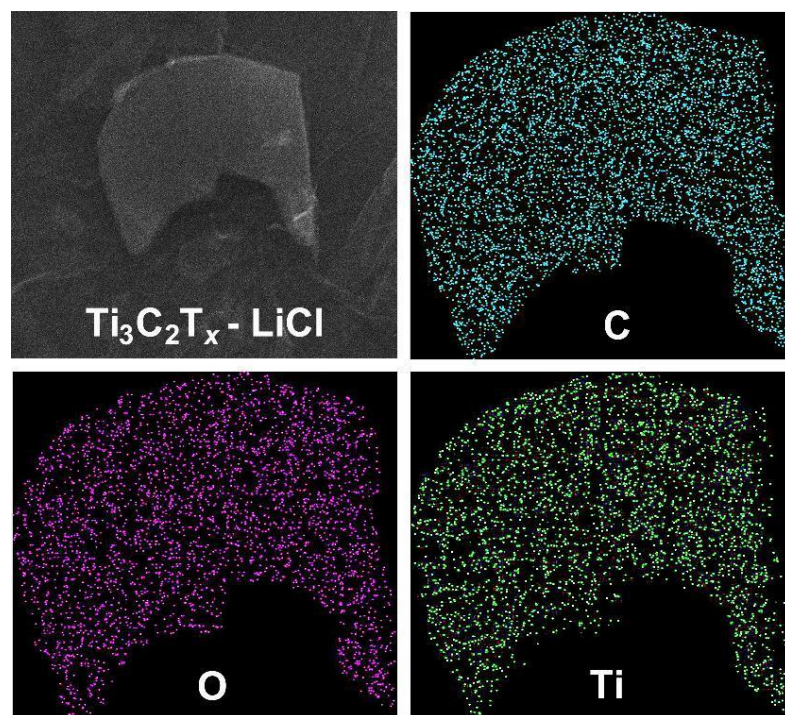


Fig. S3 The SEM image and corresponding elemental mapping of the single $\text{Ti}_3\text{C}_2\text{T}_x\text{-LiCl}$ MXene.

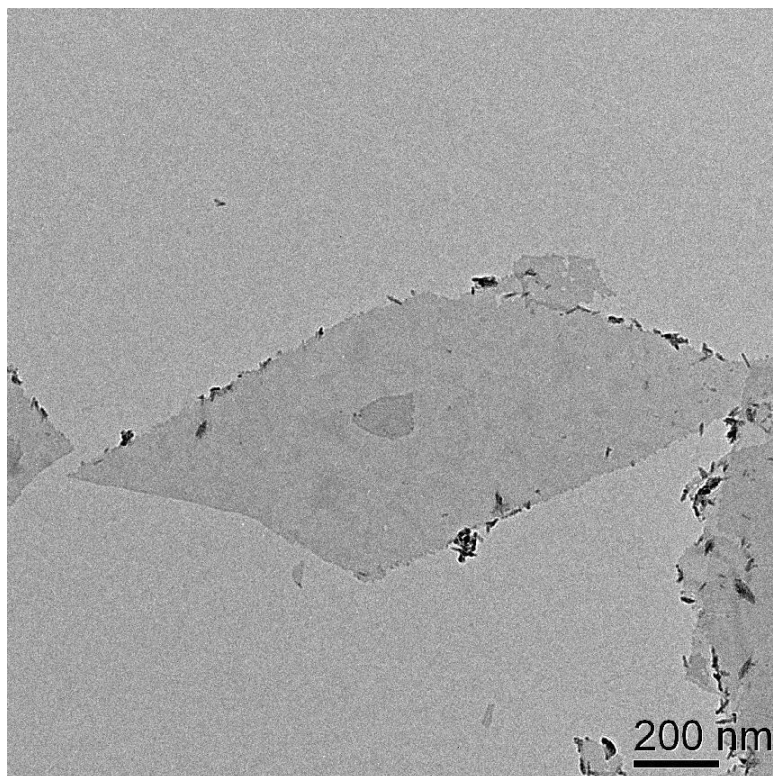


Fig. S4 The TEM image of the single $\text{Ti}_3\text{C}_2\text{T}_x$ -DMSO MXene.

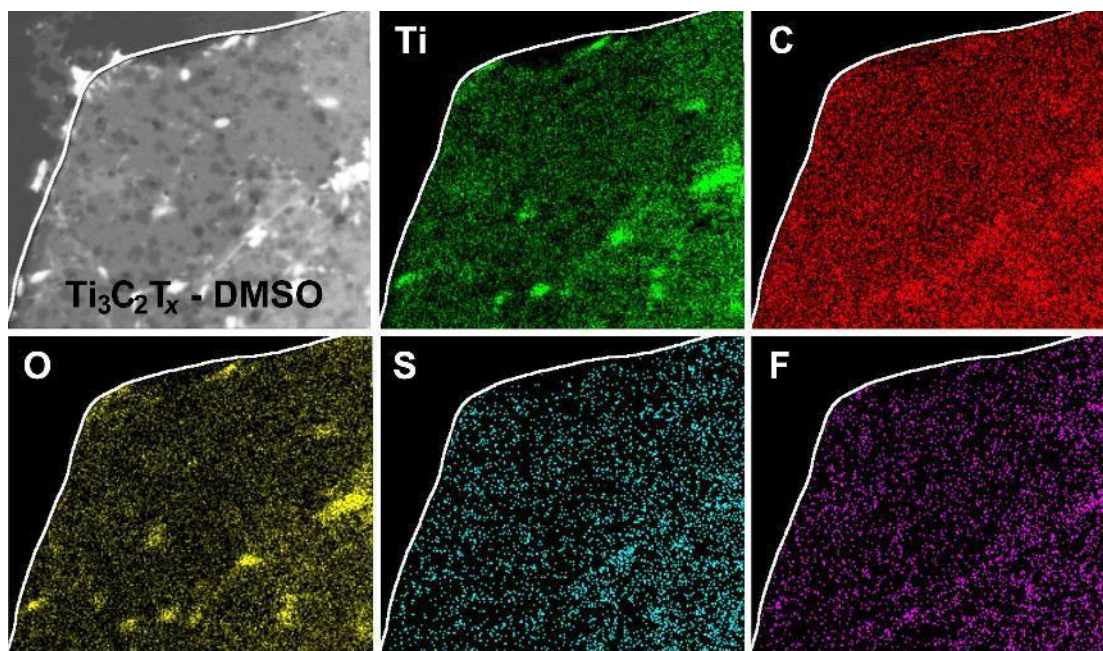


Fig. S5 The TEM image and corresponding elemental mapping of the single $\text{Ti}_3\text{C}_2\text{T}_x$ -LiCl MXene.

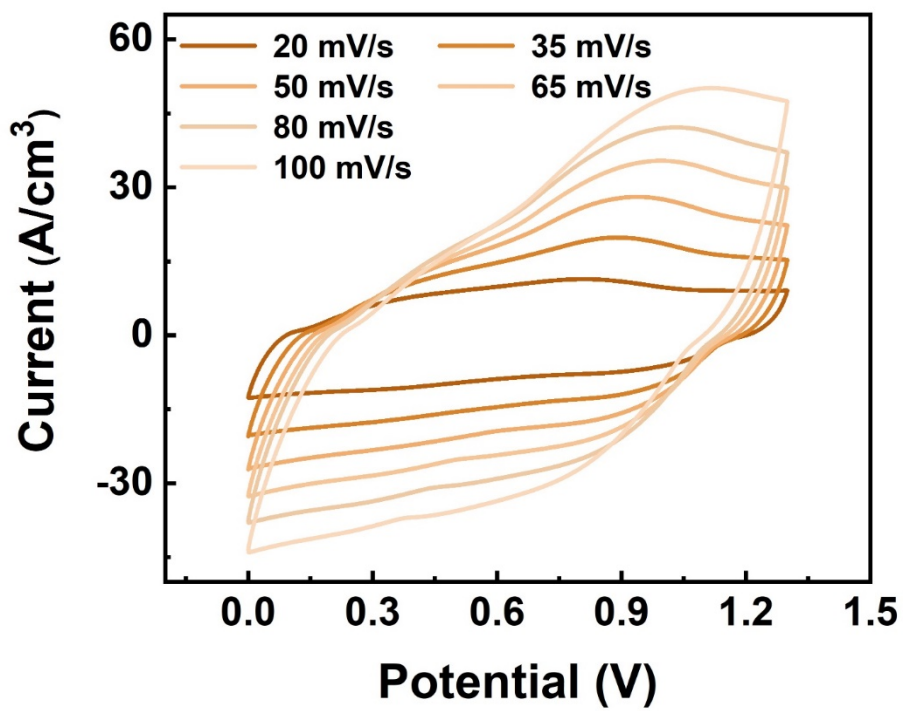


Fig. S6 The CV curves of $\text{Ti}_3\text{C}_2\text{T}_x$ -DMSO MXene-based Zn-ion MSC with $\text{K}_3\text{Co}(\text{CN})_6$ additive.

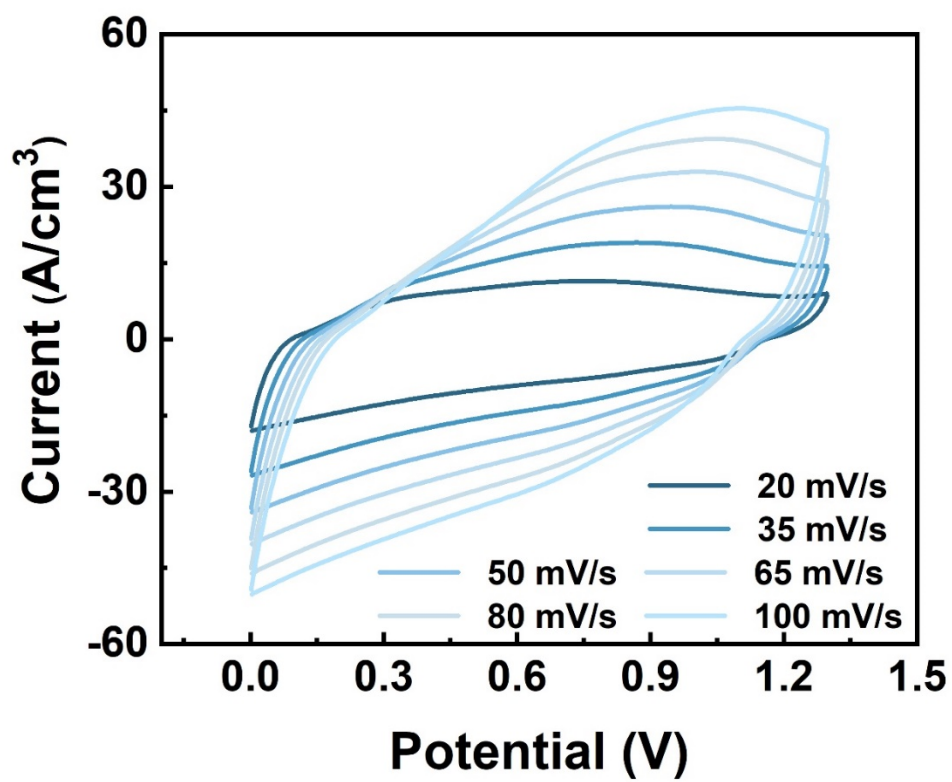


Fig. S7 The CV curves of $\text{Ti}_3\text{C}_2\text{T}_x$ -DMSO MXene-based Zn-ion MSC without additive.

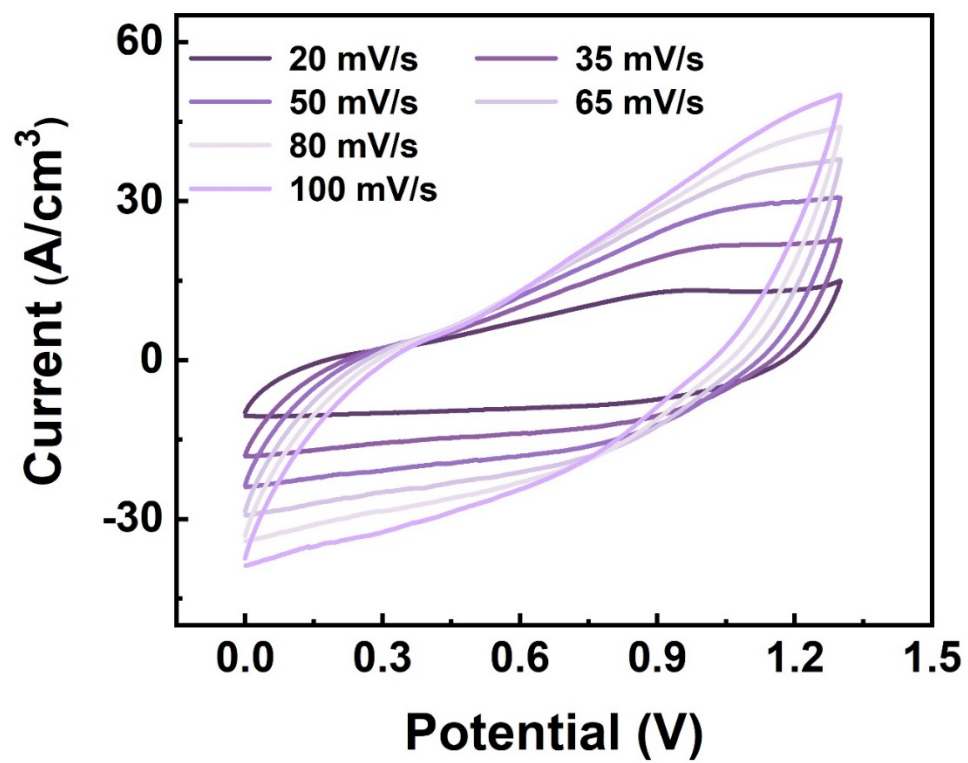


Fig. S8 The CV curves of $\text{Ti}_3\text{C}_2\text{T}_x$ -DMSO MXene-based Zn-ion MSC with CKNSe additive.

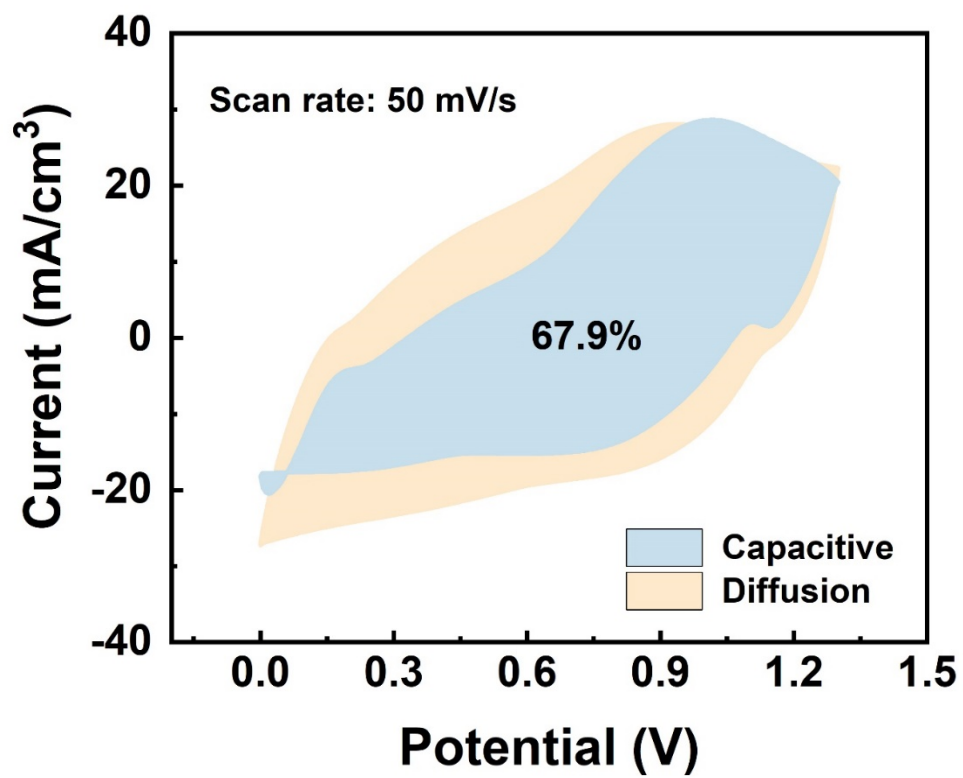


Fig. S9 Capacitive and diffusion current of the $\text{Ti}_3\text{C}_2\text{T}_x$ -DMSO cathodes based SC with $\text{K}_3\text{Co}(\text{CN})_6$ additive at a scan rate of 50 mV/s.

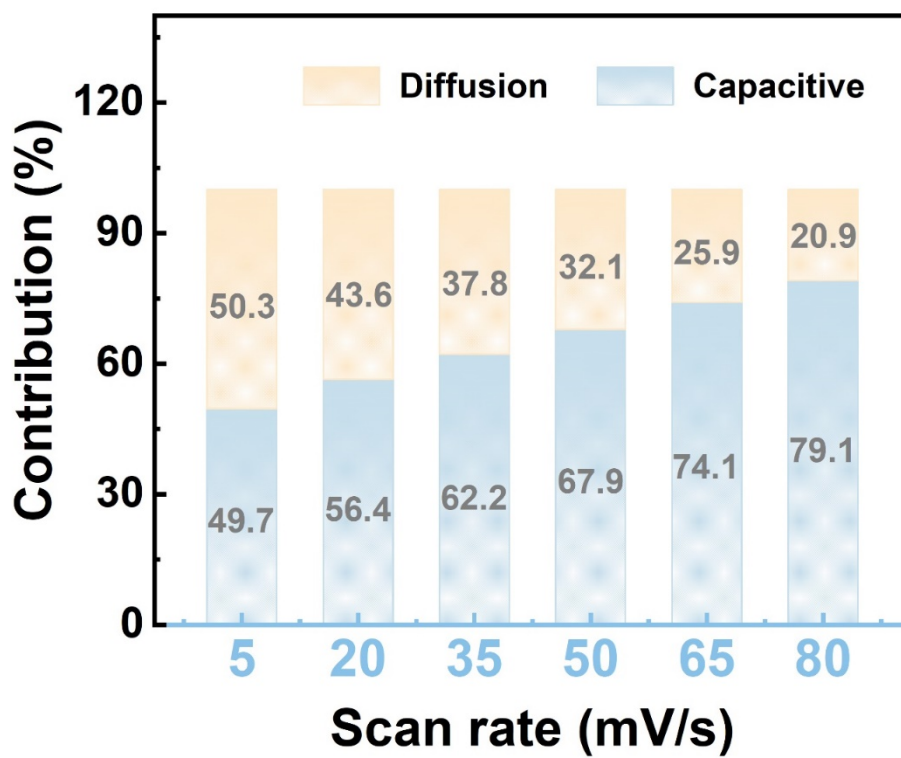


Fig. S10 Capacitive and diffusion contribution ratio of the SC at different scan rates.

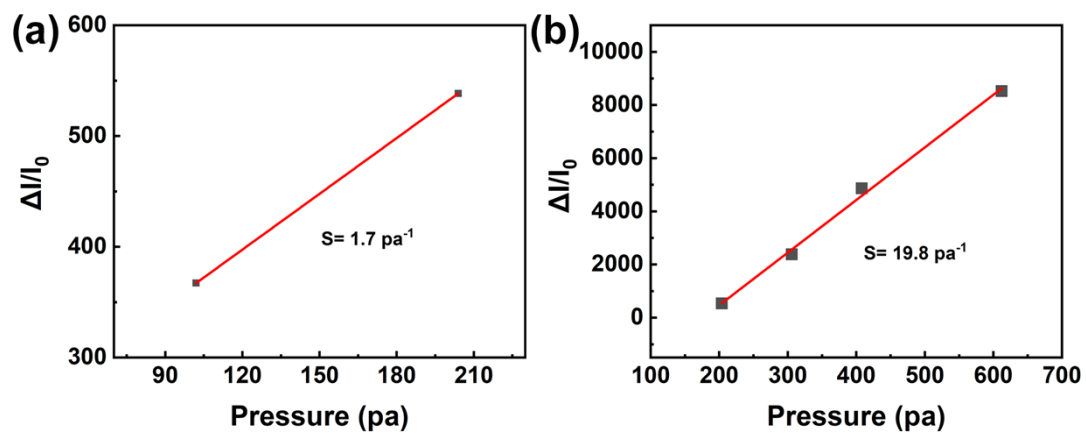


Fig. S11 Sensitivity plots of the flexible sensors under various pressure levels ($n = 3$ measurements).

Calculations of the volumetric capacitance/energy density

$$\int_0^v I dv$$

$\frac{1}{SV A}$ Volumetric capacitance could be calculated by the equations:

$$C_A =$$

Where C_A represented the specific volumetric capacitance, I was current, S stood for the scan rate, V was the potential in the CV curve, A was the volume of the devices.

The energy density and power density:

$$E = C_A \times \Delta V^2 / 7200 \quad P = E \times 3600 / \Delta t$$

E represented the energy density, P was the power density, and Δt was the total discharge time.